

33rd International Conference on Physics of Semiconductors (ICPS 2016)

Journal of Physics: Conference Series Volume 864

Beijing, China
31 July – 5 August 2016

ISBN: 978-1-5108-4720-0
ISSN: 1742-6588

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31 July to 5 August 2016, Beijing, China**

**Accepted papers received: 15 June 2017
Published online: 15 August 2017**

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